



The OMA linear photodiode array (PDA) from Princeton Instruments is the ideal sensor for high-performance, near-infrared (NIR) spectroscopy. Three models are available with spectral coverage from 800 μm up to 2.2 μm . This InGaAs detector offers outstanding sensitivity with 16-bit digitization and leads the industry with the fastest spectral rate (up to 1800 spectra/sec), lowest system read noise, and software-selectable amplifiers for either high-sensitivity or high-SNR applications. Typical OMA V applications include NIR Raman, emission, and absorbance spectroscopy. Cryogenic cooling minimizes dark noise for long exposure times.

Applications: NIR spectroscopy

Features

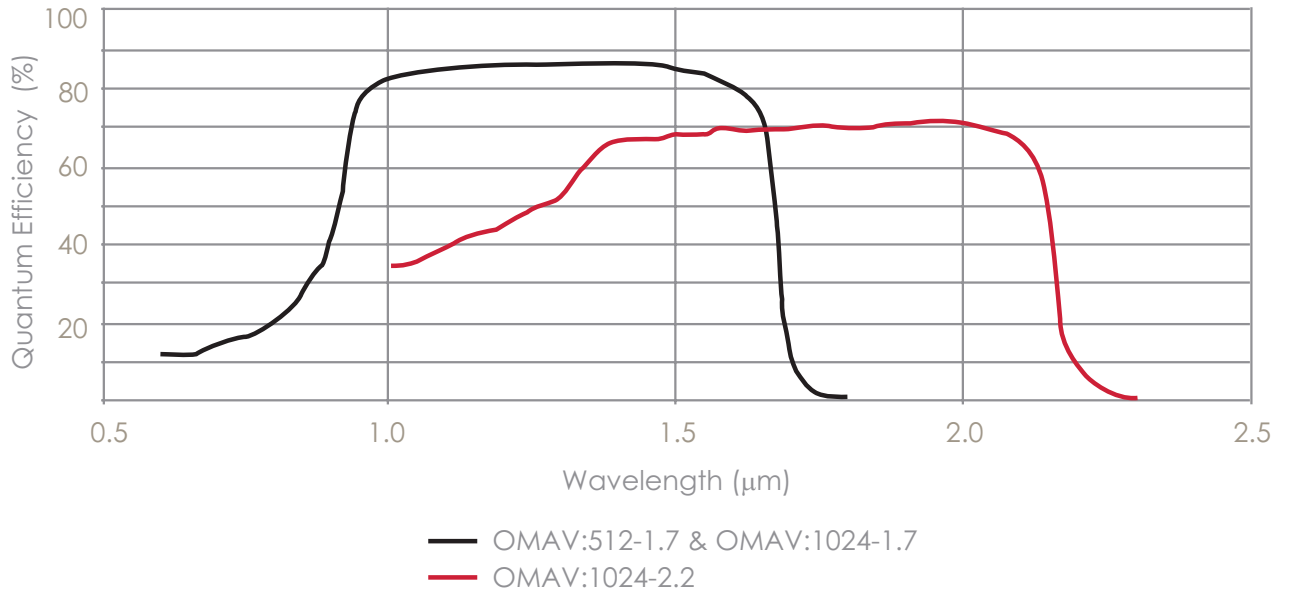
Benefits

Response up to 2.2 μm	Ideal for Imaging in NIR region
Cryogenic cooling	Cools the array from -50°C to -100°C to optimize NIR response and minimize dark noise
Software-selectable amplifiers	Exclusive feature provides choice of superior sensitivity or superior signal-to-noise ratio (SNR)
Electronic shutter	Provides integration times from 20 μsec to many minutes
High spectral data rate	Provides up to 1800 spectra/second with 1-MHz digitization
Spectrometer compatibility	Easy integration with industry-standard Acton spectrometers or other leading third-party spectrometers
“USB 2.0 interface” configuration	Seamless, plug-and-play connection to PC notebooks and desktops Easy OEM integration
“PCI interface” configuration	Industry standard for fast data transfer over long distances
WinSpec and PVCAM®	Offers powerful, easy-to-use set of Windows® GUI controls Automates data acquisition, analysis, and display
Linux® drives and SITK™ plug-in for National Instruments' LabVIEW™	Extends system utility

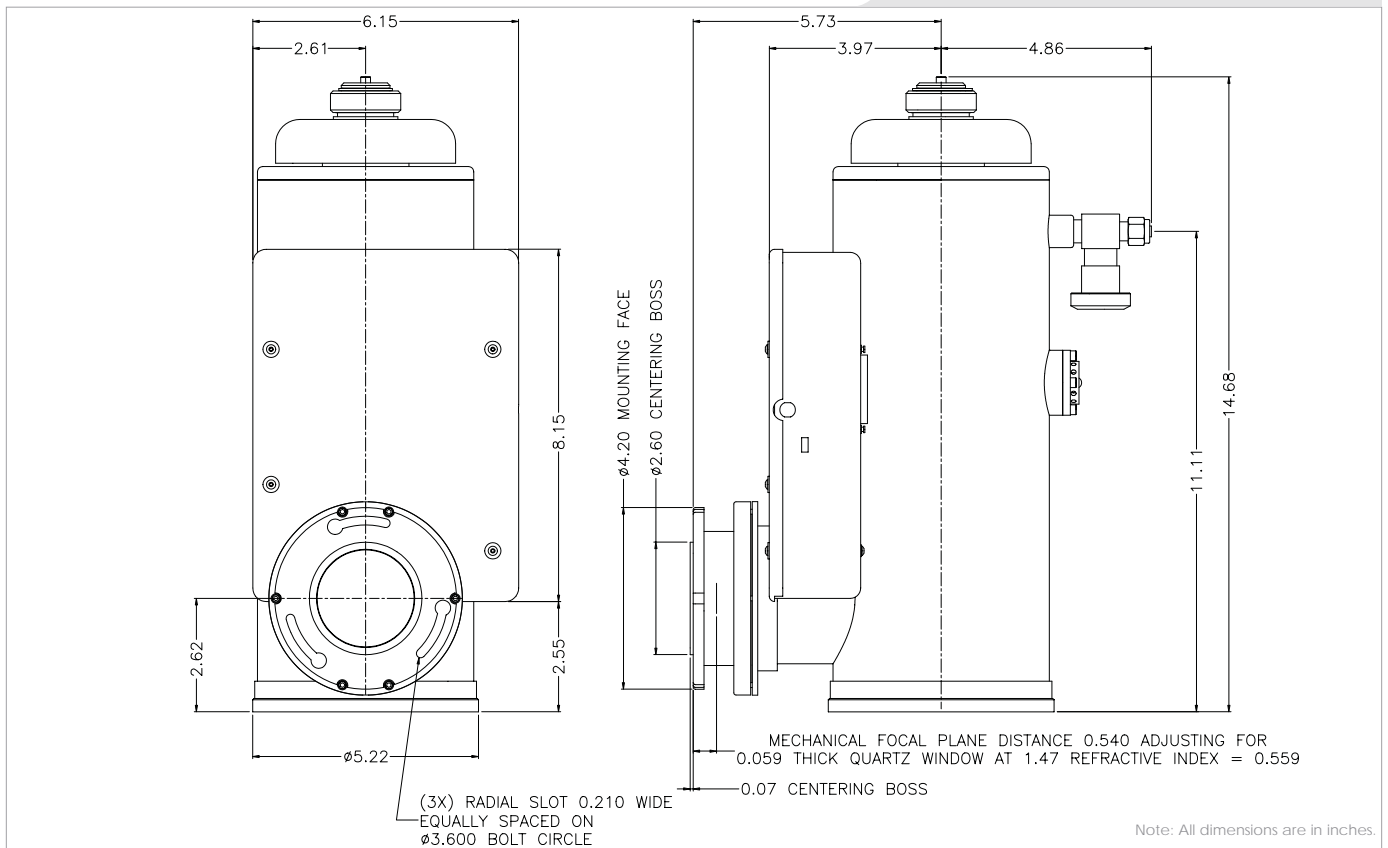
OMA V Specifications

Image sensor	Linear InGaAs photodiode array					
	OMAV:512-1.7		OMAV:1024-1.7		OMAV:1024-2.2	
Format	512 x 1, 50 x 500 μm		1024 x 1, 25 x 500 μm		1024 x 1, 25 x 500 μm	
Spectral Rate	1800 spectra/sec		900 spectra/sec		900 spectra/sec	
	1.7 μm			2.2 μm		
Spectral range	0.8 - 1.7 μm			1.0 - 2.2 μm		
	Minimum		Typical		Maximum	
System read noise						
low gain	5000 e-		6000 e-		7000 e-	
high gain	500 e-		650 e-		520 e-	
	Typical		Maximum		Typical	
Dark Signal*						
low gain	2.3 ke-/p/s		3 ke-/p/s		1.2 Me-/p/s	
high gain	3.2 ke-/p/s		5 ke-/p/s		1.5 Me-/p/s	
	All OMA-V models					
	Minimum			Typical		
Spectrometric Well Capacity						
low gain	100 Me-			130 Me-		
high gain	4 Me-			4.7 Me-		
	Minimum		Typical		Maximum	
Nominal Gain						
low gain	1525 e-/ct		1750 e-/ct		2000 e-/ct	
high gain	61 e-/ct		65 e-/ct		76 e-/ct	
Response Non-linearity						
low gain			<1.5%			
high gain			<2.5%			
	Typical			Maximum		
Response non-uniformity	+/- 5%			+/- 10%		
Digitization	16 bits					
Scan Rate	1 MHz					
Minimum Exposure time	20 μsec					
Thermostating precision	+/- 0.05 across temperature range					
Operating Temperature	-50°C to -100°C					
Blemish specifications	Grade A: <1% defects, minimum of 5 active pixels between any two inactive pixels					

Notes: All specifications subject to change.
*includes devices dark current @ -100°C looking at a 77K scene.



OMA V Drawing



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